Features

- BV_{CEO} > 45V, 60V & 80V
- I_c = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)}$ < 500mV @ 0.5A
- Gain Groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary PNP Types: BCX51, 52, and 53
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The BCX5616QTA is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

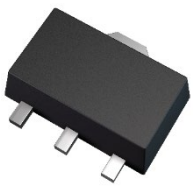
Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads. Solderable per MIL-STD-202 Method 208 e3
- Weight: 0.055 grams (Approximate)

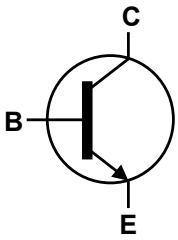
Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

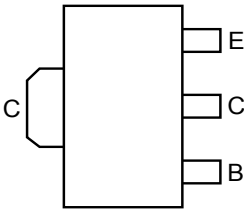
SOT89



Top View



Device Symbol



Top View
Pin-Out

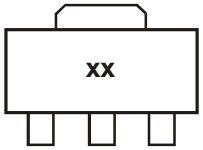
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCX54TA	Standard	BA	7	12	1,000
BCX5410TA	Standard	BC	7	12	1,000
BCX5416TA	Standard	BD	7	12	1,000
BCX5416-13R	Standard	BD	13	12	4,000
BCX55TA	Standard	BE	7	12	1,000
BCX5510TA	Standard	BG	7	12	1,000
BCX5516TA	Standard	BM	7	12	1,000
BCX56TA	Standard	BH	7	12	1,000
BCX5610TA	Standard	BK	7	12	1,000
BCX5616TA	Standard	BL	7	12	1,000
BCX5616TC	Standard	BL	13	12	4,000
BCX5410TC	Standard	BC	13	12	4,000
BCX5416TC	Standard	BD	13	12	4,000
BCX54TC	Standard	BA	13	12	4,000
BCX5510TC	Standard	BG	13	12	4,000
BCX5516TC	Standard	BM	13	12	4,000
BCX55TC	Standard	BE	13	12	4,000
BCX5610TC	Standard	BK	13	12	4,000
BCX56TC	Standard	BH	13	12	4,000
BCX5616QTA	Automotive	Refer to https://www.diodes.com/assets/Datasheets/BCX5616Q.pdf			

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT89



xx = Product Type Marking Code, as follows:

BCX54 = BA	BCX55 = BE	BCX56 = BH
BCX5410 = BC	BCX5510 = BG	BCX5610 = BK
BCX5416 = BD	BCX5516 = BM	BCX5616 = BL

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX54	BCX55	BCX56	Unit
Collector-Base Voltage	V_{CBO}	45	60	100	V
Collector-Emitter Voltage	V_{CEO}	45	60	80	V
Emitter-Base Voltage	V_{EBO}	6			V
Continuous Collector Current	I_C	1			A
Peak Pulse Collector Current	I_{CM}	2			
Continuous Base Current	I_B	100			mA
Peak Pulse Base Current	I_{BM}	200			

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

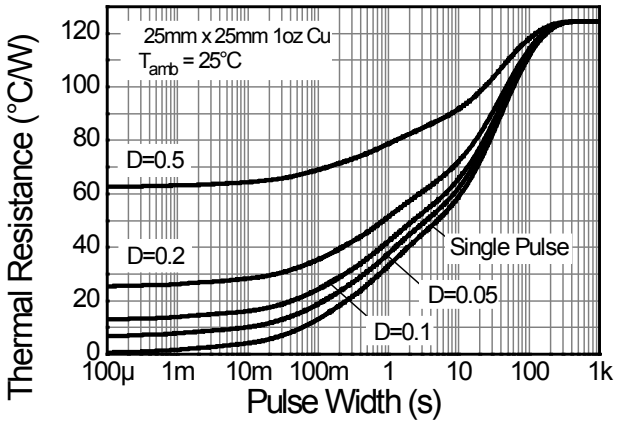
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	1	W
	(Note 6)		1.5	
	(Note 7)		2.0	
Thermal Resistance, Junction to Ambient Air	(Note 5)	$R_{\theta JA}$	125	°C/W
	(Note 6)		83	
	(Note 7)		60	
Thermal Resistance, Junction to Lead	(Note 8)	$R_{\theta JL}$	13	°C/W
Thermal Resistance, Junction to Case	(Note 9)	$R_{\theta JC}$	27	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-65 to +150	°C

ESD Ratings (Note 10)

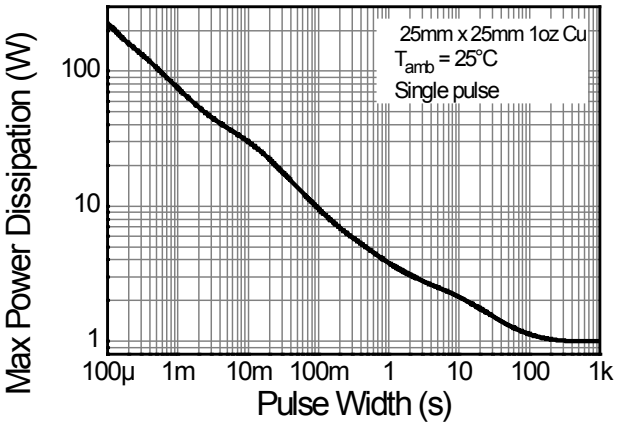
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still-air conditions whilst operating in a steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
7. Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
8. Thermal resistance from junction to solder-point (on the exposed collector pad).
9. Thermal resistance from junction to the top of the case.
10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

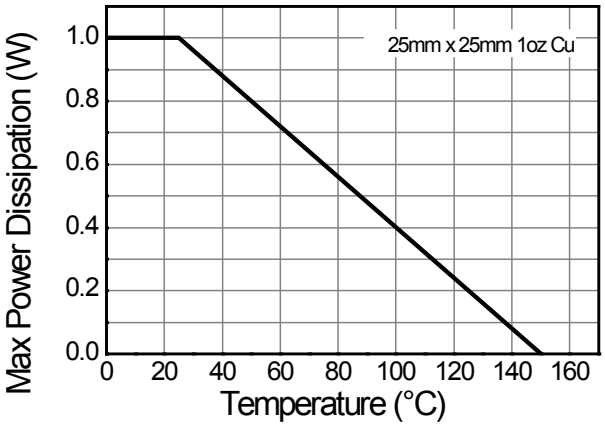
Thermal Characteristics and Derating Information



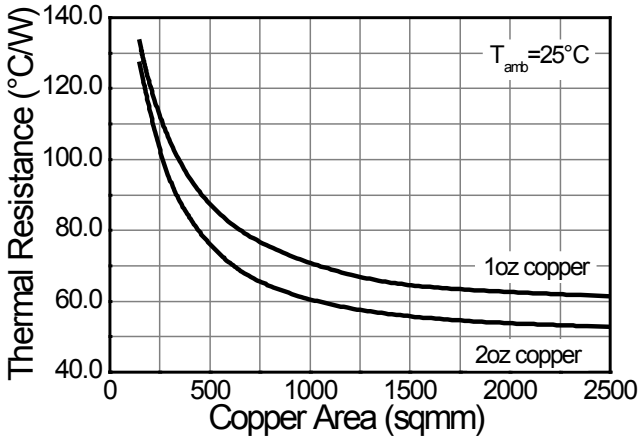
Transient Thermal Impedance

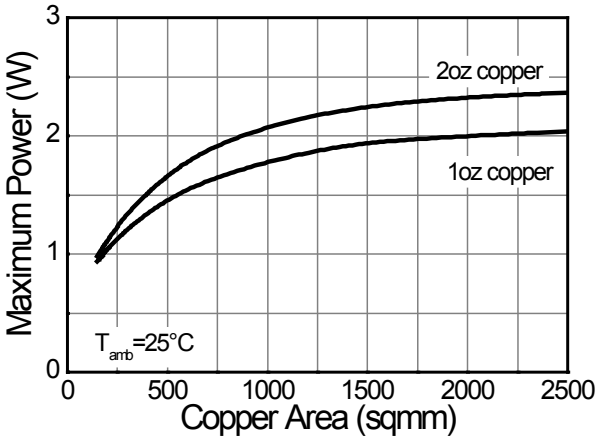


Pulse Power Dissipation



Derating Curve





Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BCX54	BV_{CBO}	45	—	—	V	I_C = 100µA
	BCX55		60				
	BCX56		100				
Collector-Emitter Breakdown Voltage (Note 11)	BCX54	BV_{CEO}	45	—	—	V	I_C = 10mA
	BCX55		60				
	BCX56		80				
Emitter-Base Breakdown Voltage		BV_{EBO}	6	—	—	V	I_E = 100µA
Collector Cut-Off Current		I_{CBO}	—	—	0.1 20	µA	V_{CB} = 30V V_{CB} = 30V, T_A = +150°C
Emitter Cut-Off Current		I_{EBO}	—	—	20	nA	V_{EB} = 5V
Static Forward Current Transfer Ratio (Note 11)	All versions	h_{FE}	25 40 25	— — —	— 250 —	—	I_C = 5mA, V_{CE} = 2V I_C = 150mA, V_{CE} = 2V I_C = 500mA, V_{CE} = 2V
	10 gain grp		63	—	160		I_C = 150mA, V_{CE} = 2V
	16 gain grp		100	—	250		I_C = 150mA, V_{CE} = 2V
Collector-Emitter Saturation Voltage (Note 11)		$V_{CE(sat)}$	—	—	0.5	V	I_C = 500mA, I_B = 50mA
Base-Emitter Turn-On Voltage (Note 11)		$V_{BE(on)}$	—	—	1.0	V	I_C = 500mA, V_{CE} = 2V
Transition Frequency		f_T	150	—	—	MHz	I_C = 50mA, V_{CE} = 10V f = 100MHz
Output Capacitance		C_{obo}	—	—	25	pF	V_{CB} = 10V, f = 1MHz

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

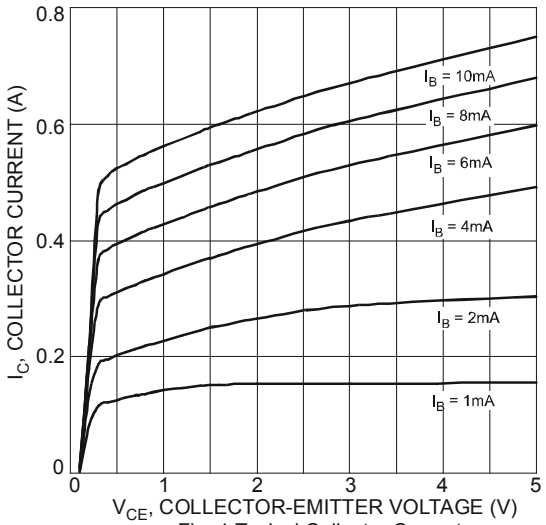


Fig. 1 Typical Collector Current vs. Collector-Emitter Voltage

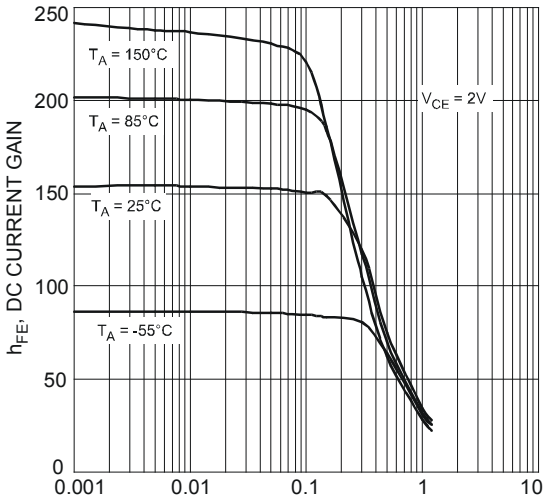


Fig. 2 Typical DC Current Gain vs. Collector Current

Typical Electrical Characteristics (continued)

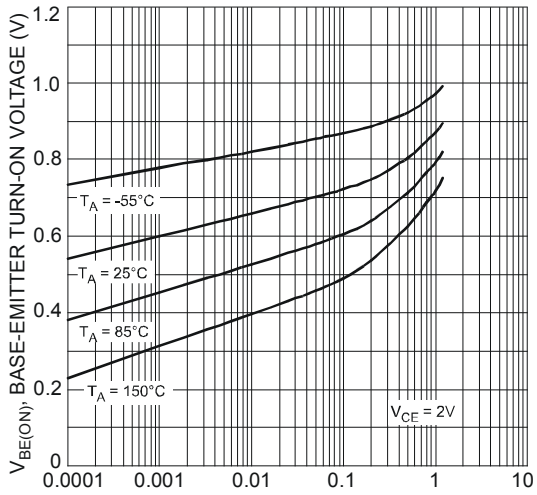


Fig. 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

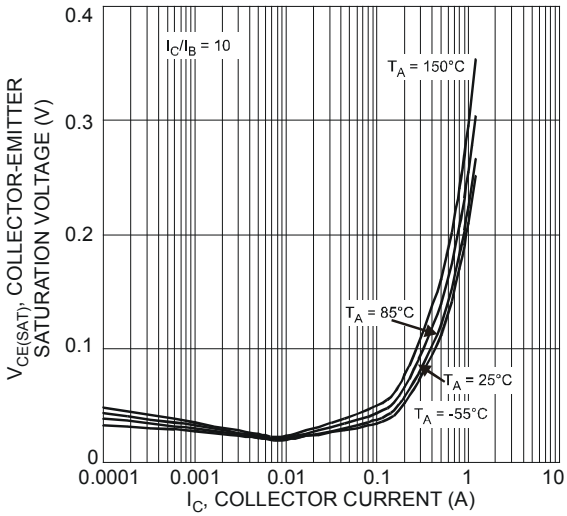


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

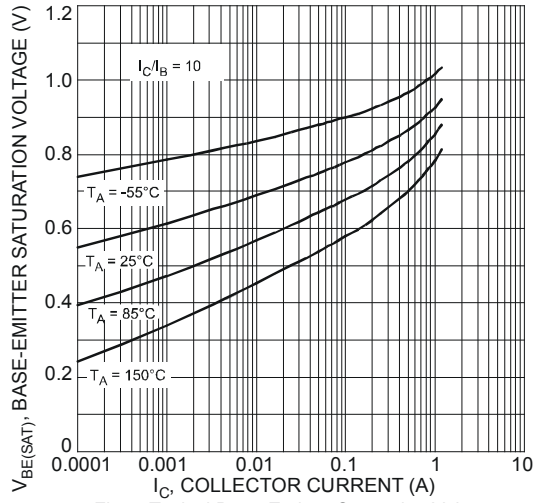


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

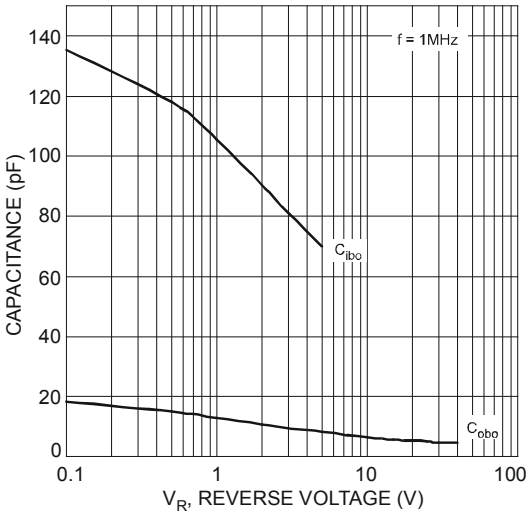


Fig. 6 Typical Capacitance Characteristics

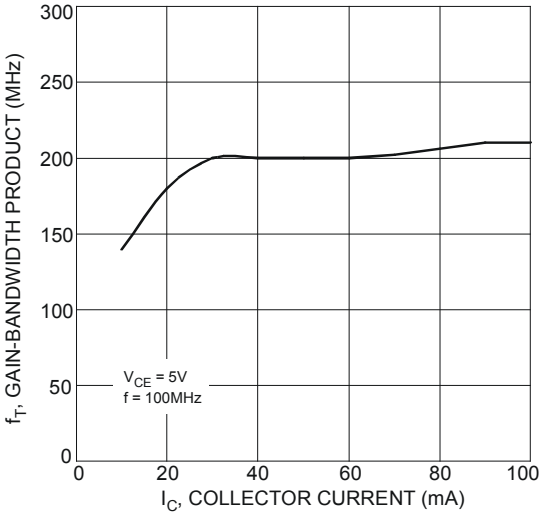
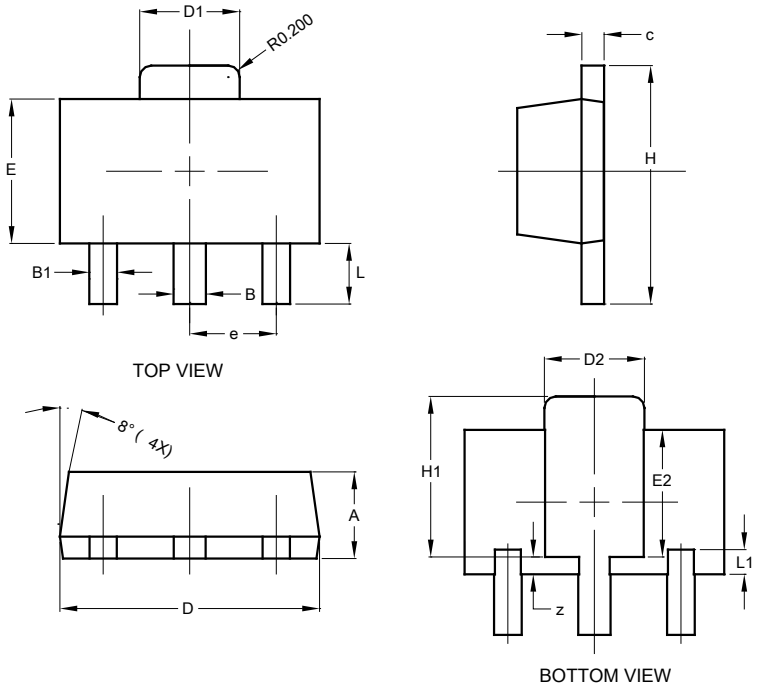


Fig. 7 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

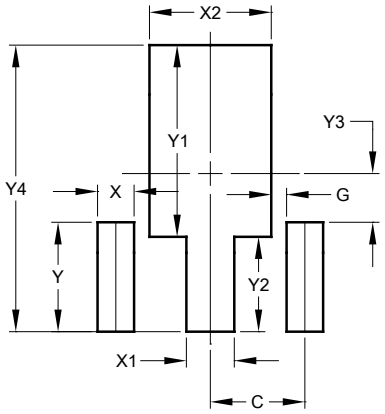


SOT89			
Dim	**Min**	**Max**	**Typ**
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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